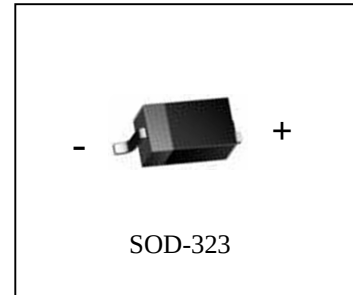


BAV19WS~BAV21WS

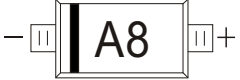
SWITCHING DIODE

FEATURES

- Low Reverse Current
- Surface Mount Package Ideally Suited for Automatic Insertion
- Fast Switching Speed
- For General Purpose Switching Applications



MARKING:

BAV19WS A8	BAV20WS T2	BAV21WS T3
		

The marking bar indicates the cathode

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

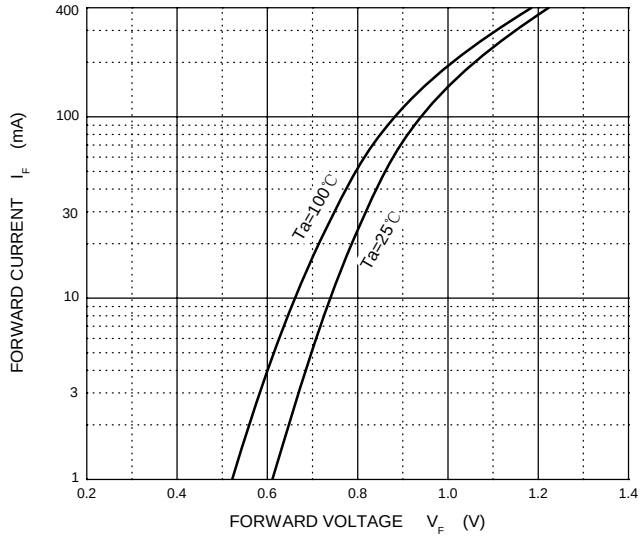
Symbol	Parameter	Value			Unit
		BAV19WS	BAV20WS	BAV21WS	
V_{RM}	Non-Repetitive Peak Reverse Voltage	120	200	250	V
V_{RRM}	Peak Repetitive Reverse Voltage	100	150	200	V
V_{RWM}	Working Peak Reverse Voltage				
$V_{R(RMS)}$	RMS Reverse Voltage	71	106	141	V
I_O	Average Rectified Output Current	200			mA
I_{FSM}	Non-repetitive Peak Forward Surge Current @ $t=8.3\text{ms}$	2.0			A
P_D	Power Dissipation	250			mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	500			$^{\circ}\text{C/W}$
T_j	Junction Temperature	150			$^{\circ}\text{C}$
T_{stg}	Storage Temperature	$-55\sim+150$			$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS($T_a=25^{\circ}\text{C}$ unless otherwise specified)

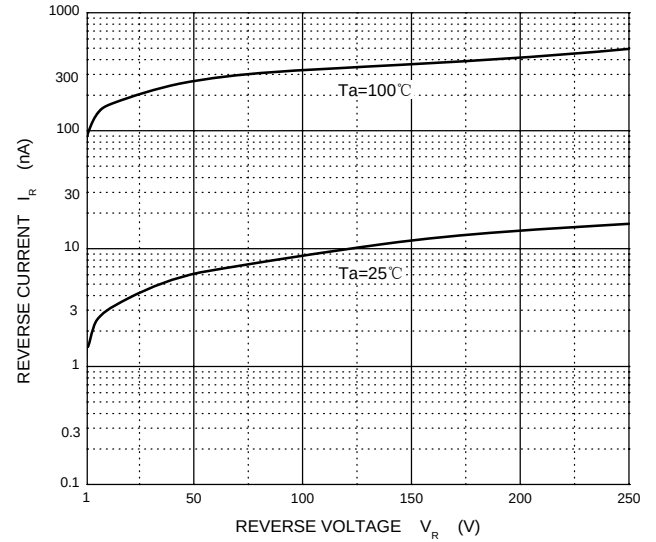
Parameter	Symbol	Test conditions		Min	Typ	Max	Unit
Reverse current	I_R	$V_R=100\text{V}$	BAV19WS			0.1	μA
		$V_R=150\text{V}$	BAV20WS			0.1	
		$V_R=200\text{V}$	BAV21WS			0.1	
Forward voltage	V_F	$I_F=100\text{mA}$				1	V
		$I_F=200\text{mA}$				1.25	
Total capacitance	C_{tot}	$V_R=0\text{V}, f=1\text{MHz}$				5	pF
Reverse recovery time	t_{rr}	$I_F=I_R=30\text{mA}, I_{rr}=0.1*I_R, R_L=100\Omega$				50	ns

BAV19WS~BAV21WS Typical Characteristics

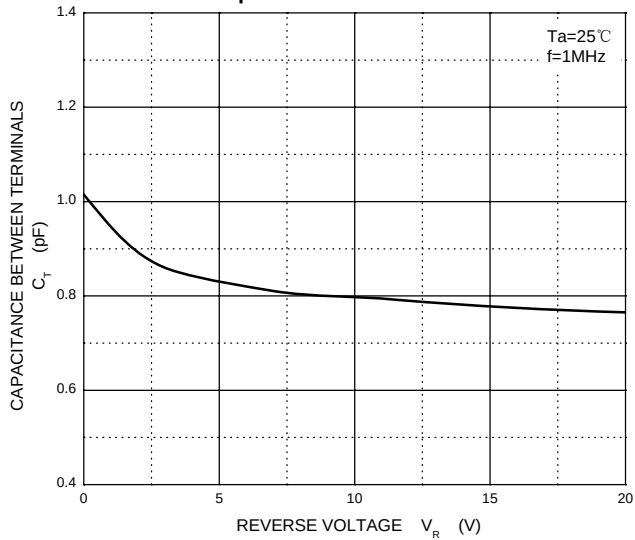
Forward Characteristics



Reverse Characteristics



Capacitance Characteristics



Power Derating Curve

